

# NPN General Purpose Transistor

## NST846BF3T5G

The NST846BF3T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-1123 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

### Features

- $h_{FE}$ , 200–450
- Low  $V_{CE(sat)}$ ,  $\leq 0.25$  V
- Reduces Board Space
- This is a Halide-Free Device
- This is a Pb-Free Device

### MAXIMUM RATINGS

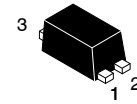
Symbol	Rating	Value	Unit
$V_{CEO}$	Collector–Emitter Voltage	65	Vdc
$V_{CBO}$	Collector–Base Voltage	80	Vdc
$V_{EBO}$	Emitter–Base Voltage	6.0	Vdc
$I_C$	Collector Current – Continuous	100	mAdc

### THERMAL CHARACTERISTICS

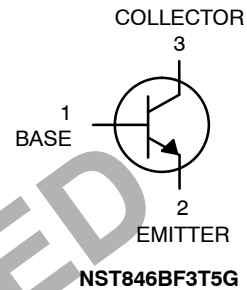
Symbol	Characteristic	Max	Unit
$P_D$ (Note 1)	Total Device Dissipation, $T_A = 25^\circ\text{C}$	290	mW
	Derate above $25^\circ\text{C}$	2.3	mW/ $^\circ\text{C}$
$R_{\theta JA}$ (Note 1)	Thermal Resistance, Junction–to–Ambient	432	$^\circ\text{C}/\text{W}$
$P_D$ (Note 2)	Total Device Dissipation, $T_A = 25^\circ\text{C}$	347	mW
	Derate above $25^\circ\text{C}$	2.8	mW/ $^\circ\text{C}$
$R_{\theta JA}$ (Note 2)	Thermal Resistance, Junction–to–Ambient	360	$^\circ\text{C}/\text{W}$
$R_{\psi JL}$ (Note 2)	Thermal Resistance, Junction–to–Lead 3	143	$^\circ\text{C}/\text{W}$
$T_J, T_{stg}$	Junction and Storage Temperature Range	–55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. 100 mm<sup>2</sup> 1 oz, copper traces.
2. 500 mm<sup>2</sup> 1 oz, copper traces.



SOT-1123  
CASE 524AA  
STYLE 1  
(Rotated 90° Clockwise)



### MARKING DIAGRAM



V = Device Code  
M = Date Code

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NST846BF3T5G	SOT-1123 (Pb-Free)	8,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

# NST846BF3T5G

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	65	-	-	V
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 μA, V <sub>EB</sub> = 0)	80	-	-	V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μA)	80	-	-	V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage (I <sub>E</sub> = 1.0 μA)	6.0	-	-	V
I <sub>CBO</sub>	Collector Cutoff Current (V <sub>CB</sub> = 30 V) (V <sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)	-	-	15 5.0	nA μA

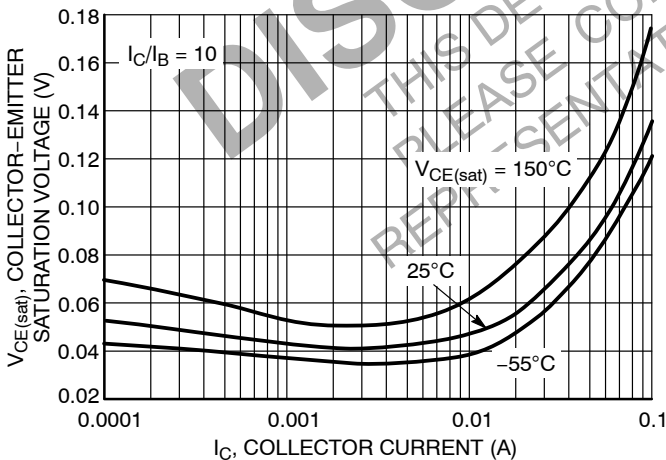
## ON CHARACTERISTICS

h <sub>FE</sub>	DC Current Gain (I <sub>C</sub> = 10 μA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V)	- 200	150 290	- 450	-
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)	- -	- -	0.25 0.6	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)	- -	0.7 0.9	- -	V
V <sub>BE(on)</sub>	Base-Emitter Voltage (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V)	580 -	660 -	700 770	mV

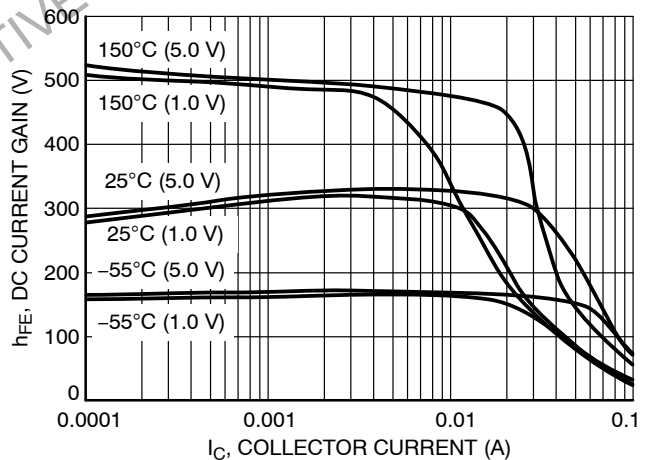
## SMALL-SIGNAL CHARACTERISTICS

f <sub>T</sub>	Current-Gain-Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz)	100	-	-	MHz
C <sub>obo</sub>	Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	-	-	4.5	pF
C <sub>ibo</sub>	Input Capacitance (V <sub>EB</sub> = 0.5 V, I <sub>C</sub> = 0 mA, f = 1.0 MHz)	-	-	10	pF
NF	Noise Figure (I <sub>C</sub> = 0.2 mA, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



**Figure 1. Collector Emitter Saturation Voltage vs. Collector Current**



**Figure 2. DC Current Gain vs. Collector Current**

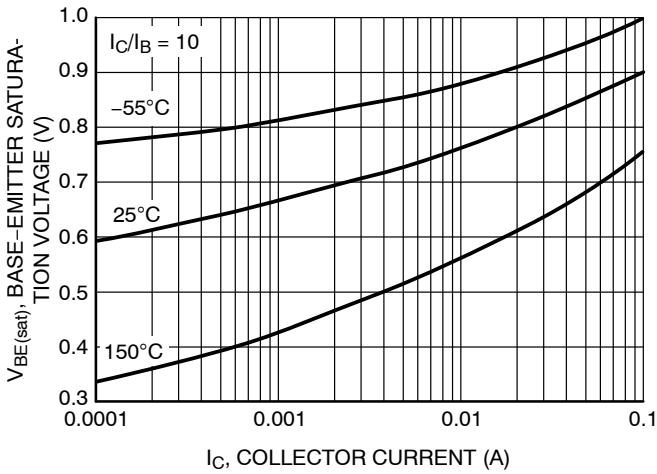


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

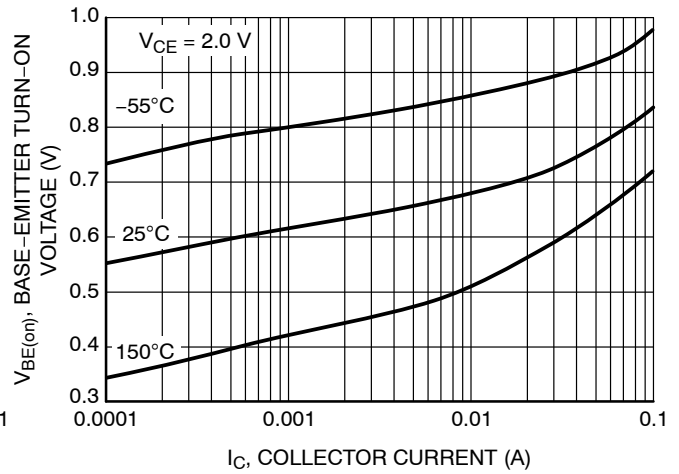


Figure 4. Base Emitter Turn-On Voltage vs. Collector Current

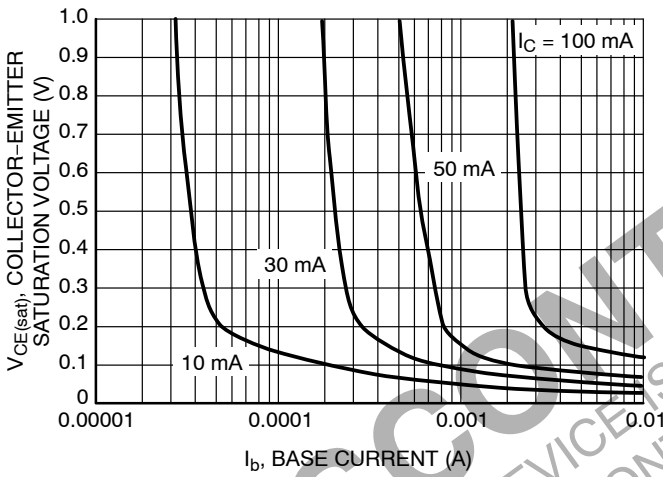


Figure 5. Saturation Region

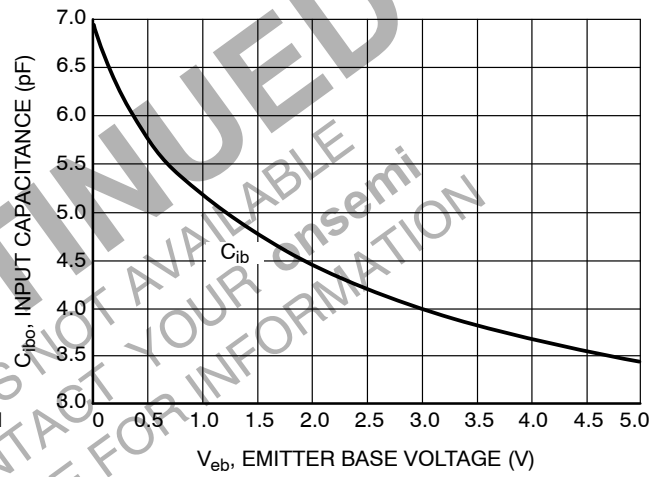


Figure 6. Input Capacitance

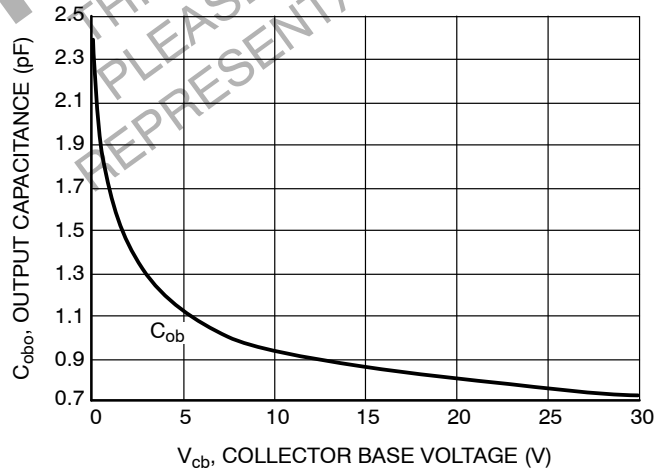


Figure 7. Output Capacitance

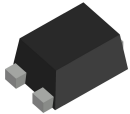
# NST846BF3T5G

## REVISION HISTORY

Revision	Description of Changes	Date
4	Data Sheet Discontinued.	01/16/2026

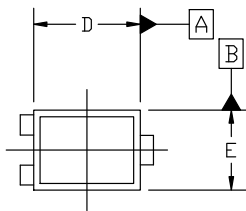
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

**DISCONTINUED**  
THIS DEVICE IS NOT AVAILABLE  
PLEASE CONTACT YOUR onsemi  
REPRESENTATIVE FOR INFORMATION

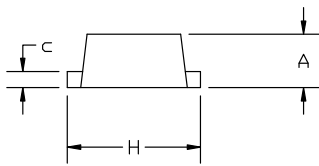


**SOT-1123 0.80x0.60x0.37, 0.35P**  
**CASE 524AA**  
**ISSUE D**

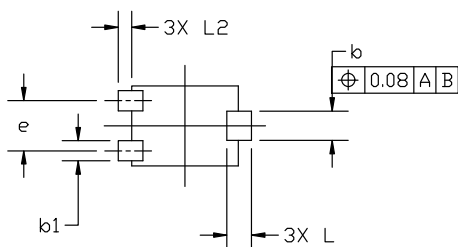
DATE 18 JAN 2024



TOP VIEW

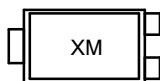


SIDE VIEW



BOTTOM VIEW

**GENERIC MARKING DIAGRAM\***



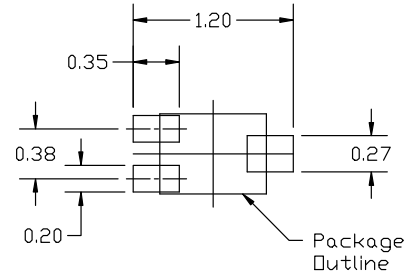
X = Specific Device Code  
M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.15	0.22	0.28
b1	0.10	0.15	0.20
c	0.07	0.12	0.17
D	0.75	0.80	0.85
E	0.55	0.60	0.65
e	0.35	0.38	0.40
H	0.950	1.000	1.050
L	0.185 REF		
L2	0.05	0.10	0.15



**RECOMMENDED MOUNTING FOOTPRINT**

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERM/D.

STYLE 1:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

STYLE 2:  
PIN 1. ANODE  
2. N/C  
3. CATHODE

STYLE 3:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE

STYLE 4:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE

STYLE 5:  
PIN 1. GATE  
2. SOURCE  
3. DRAIN

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<b>DESCRIPTION:</b>	<b>SOT-1123 0.80x0.60x0.37, 0.35P</b>	<b>PAGE 1 OF 1</b>

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